
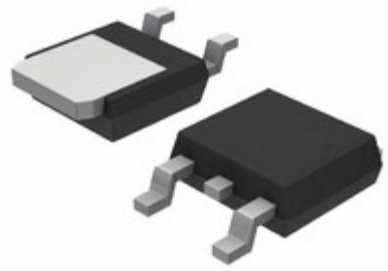






	<h2 style="color: red;">NTD20N06T4G</h2>
	<p>Hersteller-Teilenummer: NTD20N06T4G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 20A DPAK</p> <hr/> <p>Datenblätter:  NTD20N06T4G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 154407 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD20N06T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 20A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	154407 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.88W (Ta), 60W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	20A (Ta)
Rds On (Max) @ Id, Vgs	46 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1015pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)


NTD20N06T4G ist neu im Original, Suche NTD20N06T4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD20N06T4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD20N06T4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD20P03HDLT4 AMI Semiconductor / ON Semiconductor NTD20P03HDLT4 ON</p>	 <p>NTD20P03 ON NTD20P03 ON</p>	 <p>NTD20N06L-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A IPAK</p>	 <p>NTD20P03HDLT4G ON NTD20P03HDLT4G ON</p>
 <p>NTD20N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p>NTD20N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p>NTD20N06T4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p>NTD20P06HCT4G O NTD20P06HCT4G O</p>

heiße Teile

Mehr

 NTD18N06L-1G	 NTD18N06LG	 NTD18N06LT4G	 NTD18N06T4G	 NTD20N03
 NTD20N03G	 NTD20N03HL	 NTD20N03L27	 NTD20N03L27G	 NTD20N03L27T
 NTD20N03L27T4	 NTD20N03L27T4G	 NTD20N03RT4G	 NTD20N06	 NTD20N06-001
 NTD20N06-1G	 NTD20N06HD	 NTD20N06HDLT4G	 NTD20N06HL	 NTD20N06L
 NTD20N06L-001	 NTD20N06L-1G	 NTD20N06LG	 NTD20N06LT4	 NTD20N06LT4G
 NTD20N06V	 NTD20P03	 NTD20P03HDLT4G	 NTD20P06HCT4G	 NTD20P06HD
 NTD20P06HDLT4	 NTD20P06HL	 NTD20P06L	 NTD20P06L-001	 NTD20P06LG
 NTD20P06LT4G	 NTD23N03R-1	 NTD23N03R-1G	 NTD23N03RG	 NTD23N03RT4
 NTD23N03RT4G	 NTD24N06	 NTD24N06-1G	 NTD24N06G	 NTD24N06L
 NTD24N06L-001	 NTD24N06L-1G	 NTD24N06L4T	 NTD24N06LG	 NTD24N06LT4

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